

TECHNICAL DATA
DATA SHEET 332, REV. A**ULTRA LOW REVERSE LEAKAGE POWER SCHOTTKY RECTIFIER**
Very Low Voltage Drop**DESCRIPTION:** 200 VOLT, 15 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC SHD-1/B PACKAGE.**MAXIMUM RATINGS**ALL RATINGS ARE @ $T_C = 25\text{ }^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	200	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C=100\text{ }^\circ\text{C}$)	I_o	15	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ($t = 8.3\text{ms}$, Sine)	I_{FSM}	280	Amps
MAXIMUM JUNCTION CAPACITANCE ($V_r=5\text{V}$) (per leg)	C_T	300	pF
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R\theta_{JC}$	0.85	$^\circ\text{C/W}$
MAXIMUM OPERATING TEMPERATURE RANGE	Top	-65 to + 200	$^\circ\text{C}$
MAXIMUM STORAGE TEMPERATURE RANGE	Tstg	-65 to + 175	$^\circ\text{C}$

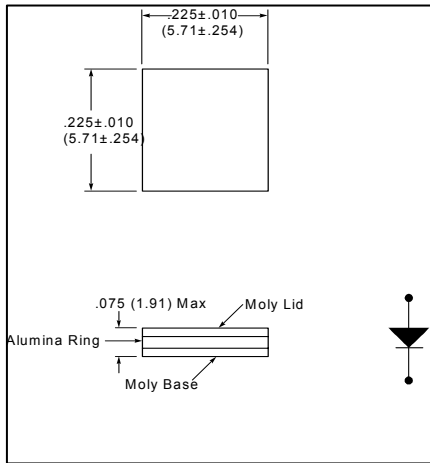
ELECTRICAL CHARACTERISTICS

CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 15\text{ Amps}$) $T_J = 25\text{ }^\circ\text{C}$ $T_J = 125\text{ }^\circ\text{C}$	V_f	0.92 0.76	Volts
MAXIMUM REVERSE CURRENT (I_r @ 200V PIV) $T_J = 25\text{ }^\circ\text{C}$ $T_J = 125\text{ }^\circ\text{C}$	I_r	0.015 1.0	mA
REVERSE RECOVERY TIME	t_{rr}	16	ns

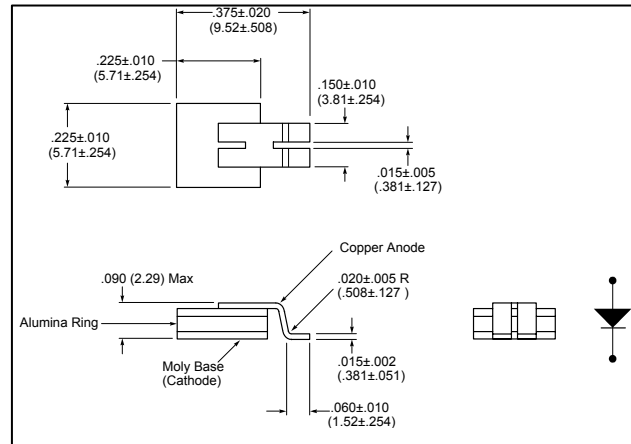
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MECHANICAL DIMENSIONS: In Inches / mm

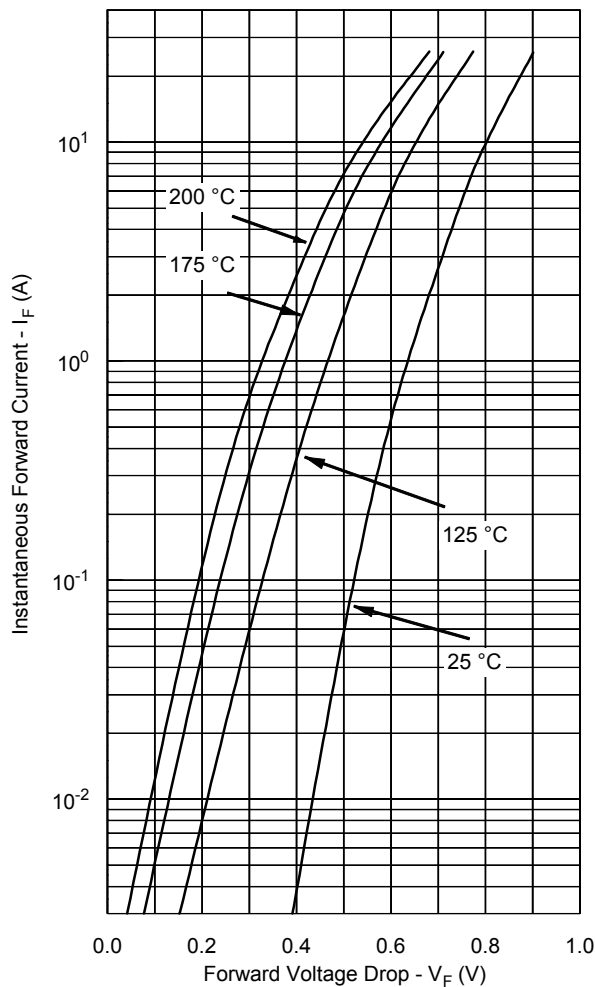
SHD-1



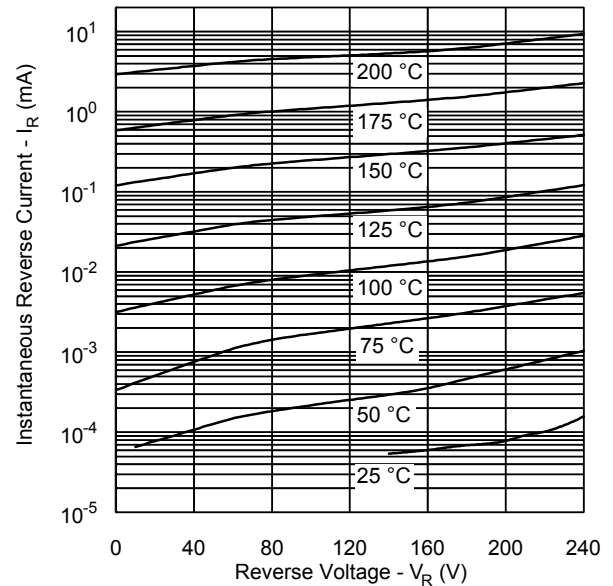
SHD-1B



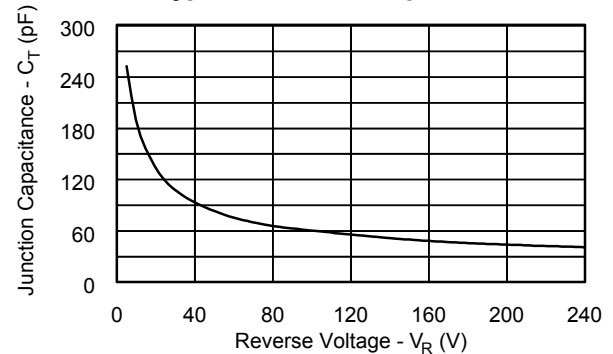
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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